



BC856AS

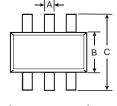
DUAL PNP SURFACE MOUNT SMALL SIGNAL TRANSISTOR

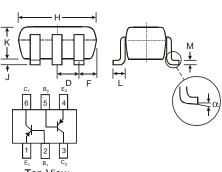
Features

- Ideally Suited for Automatic Insertion
- For Switching and AF Amplifier Applications
- Complementary NPN Types Available (BC846AS)
- Lead Free/RoHS Compliant (Note 1)
- "Green" Device (Note 4 and 5)

Mechanical Data

- Case: SOT-363
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Pin Connections: See Diagram
- Marking Codes: See Page 3
- Ordering & Date Code Information: See Page 3
- Weight: 0.006 grams (approximate)





SOT-363								
Dim	Min	Max						
Α	0.10	0.30						
В	1.15	1.35						
С	2.00 2.20							
D	0.65 Nominal							
F	0.30	0.40						
Н	1.80	2.20						
J	_	0.10						
K	0.90	1.00						
L	0.25	0.40						
М	0.10	0.25						
α	0°	8°						
ΔII Din	All Dimensions in mm							

All Dimensions in mm

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit	
Collector-Base Voltage		V_{CBO}	-80	V	
Collector-Emitter Voltage		V_{CEO}	-65	V	
Emitter-Base Voltage		V_{EBO}	-5.0	V	
Collector Current		lc	-100	mA	
Peak Collector Current		I _{CM}	-200	mA	
Peak Emitter Current		I _{EM}	-200	mA	
Power Dissipation	(Note 2)	P_d	200	mW	
Thermal Resistance, Junction to Ambient	(Note 2)	$R_{ heta JA}$	625	°C/W	
Operating and Storage Temperature Range		T _j , T _{stg}	-65 to +150	°C	

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage	(Note 3)	V _{(BR)CBO}	-80	_	_	V	$I_C = 10\mu A, I_B = 0$
Collector-Emitter Breakdown Voltage	(Note 3)	V _{(BR)CEO}	-65	_	_	V	$I_C = 10 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	(Note 3)	V _{(BR)EBO}	-5	_	_	V	$I_E = 1 \mu A, I_C = 0$
DC Current Gain	(Note 3)	h _{FE}	125	180	250	_	$V_{CE} = -5.0V, I_{C} = -2.0mA$
Collector-Emitter Saturation Voltage	(Note 3)	V _{CE(SAT)}	_	-75 -250	-300 -650	mV	$I_C = -10 \text{mA}, I_B = -0.5 \text{mA}$ $I_C = -100 \text{mA}, I_B = -5.0 \text{mA}$
Base-Emitter Saturation Voltage	(Note 3)	V _{BE(SAT)}		-700 -850	_	mV	$I_C = -10 \text{mA}, I_B = -0.5 \text{mA}$ $I_C = -100 \text{mA}, I_B = -5.0 \text{mA}$
Base-Emitter Voltage	(Note 3)	V _{BE(ON)}	-600 —	-650 —	-750 -820	mV	$V_{CE} = -5.0V, I_{C} = -2.0mA$ $V_{CE} = -5.0V, I_{C} = -10mA$
Collector-Cutoff Current	(Note 3)	I _{CES} I _{CBO} I _{CBO}	_ _ _	_ _ _	-15 -15 -4.0	nA nA μA	V _{CB} = -80V V _{CB} = -30V V _{CB} = -30V, T _A = 150°C
Gain Bandwidth Product		f_T	100	_	_	MHz	V _{CE} = -5.0V, I _C = -10mA, f = 100MHz
Collector-Base Capacitance		Ссв	_	3	_	pF	V _{CB} = -10V, f = 1.0MHz

Notes: 1.

- 1. No purposefully added lead.
- 2. Device mounted on FR-4 PCB; pad layout as shown on page 3 or on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 3. Short duration pulse test used to minimize self-heating effect.
- 4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.



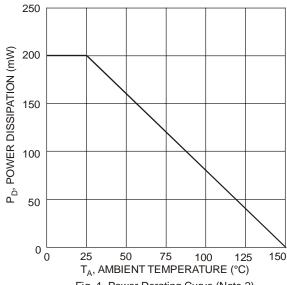


Fig. 1 Power Derating Curve (Note 2)

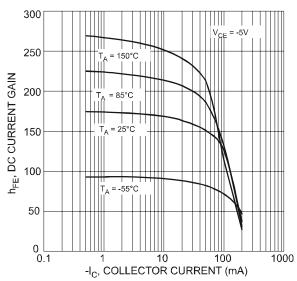


Fig. 3 Typical DC Current Gain vs. Collector Current

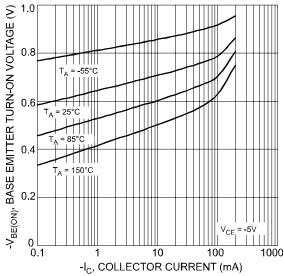


Fig. 5 Typical Base Emitter Turn-On Voltage vs. Collector Current

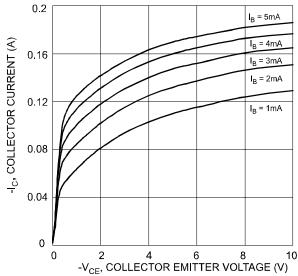


Fig. 2 Typical Collector Current vs. Collector Emitter Voltage

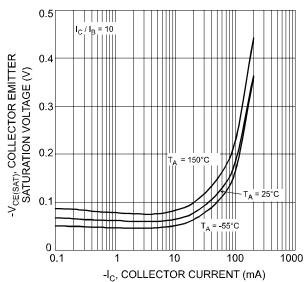


Fig. 4 Typical Collector Emitter Saturation Voltage vs. Collector Current

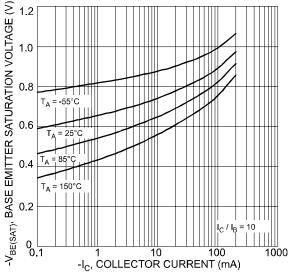
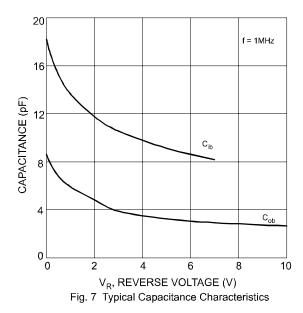
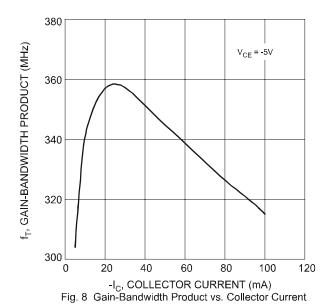


Fig. 6 Typical Base Emitter Saturation Voltage vs. Collector Current





2007

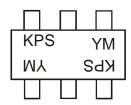


Ordering Information (Note 6)

Device	Packaging	Shipping		
BC856AS-7	SOT-363	3000/Tape & Reel		

6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



2008

KPS = Product Type Marking Code YM = Date Code Marking Y = Year ex: U = 2007 M = Month ex: 9 = September

2010

Data Code Key

Year

Code	ι	J	V	/	W		X		Y		Z	
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Λιια	Sep	Oct	Nov	Dec
WOTEH	Jan	160	IVIAI	Λþi	iviay	Juli	Jui	Aug	Sep	OCI	INOV	Dec
Code	1	2	3	4	5	6	7	R	9	0	N	D

2009

IMPORTANT NOTICE

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. Diodes Incorporated does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on our website, harmless against all damages.

LIFE SUPPORT

Diodes Incorporated products are not authorized for use as critical components in life support devices or systems without the expressed written approval of the President of Diodes Incorporated.

2012

AMEYA360 Components Supply Platform

Authorized Distribution Brand:

























Website:

Welcome to visit www.ameya360.com

Contact Us:

Address:

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd Minhang District, Shanghai , China

> Sales:

Direct +86 (21) 6401-6692

Email amall@ameya360.com

QQ 800077892

Skype ameyasales1 ameyasales2

Customer Service :

Email service@ameya360.com

Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com